Impact of substrate pits on laser-induced damage performance of 1064-nm high-reflective coatings

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The laser damage resistance of coatings in high-power laser systems depends significantly on the surface quality of the substrate. In our experiment, pits were precisely fabricated on the surface of fused silica substrate using a femtosecond laser processing bench. The HfO2/SiO2 high-reflective coatings at 1064 nm were deposited by conventional e-beam evaporation onto fused silica substrates with and without pits, respectively. The internal crack that was induced by the substrate geometrical structure was first observed in our experiment. The laser-induced damage threshold test showed negative effects of the substrate pits on the laser resistance of high-reflective coatings.

This report focuses on the damage of HfO2/SiO2 multilayer coatings induced by the pits on substrate. The role of laser-induced damage in optical materials can be both negative (a factor that limits the resistance of laser-induced damage performance in high-power laser systems) and positive (providing a tool for material fabrication and modification). In our experiment, an 800-nm-femtosecond laser was used for fabricating micro-pits on the substrate, and a 1064-nm-nanosecond laser was used for damage testing. The pits were precisely fabricated by femtosecond laser to prevent the emergence of subsurface cracks, which might be induced during cold machining process. The high-reflective (HR) coatings were then coated on the substrates with and without pits, and the LIDT was tested. The damage morphologies by a nanosecond laser with a wavelength of 1064 nm were shown to indicate the damage process and the cause of damage. A theoretical study was designed to investigate the influence of |E|2 distributions on the damage behavior of the coatings on the pits. Our results demonstrated exactly that the impact of pits defects affect the damage behavior of HR coatings.

All experiments were conducted on fused silica with dimension of 50 mm in diameter and 5 mm in thickness, which exhibits less than 0.8 nm of RMS surface roughness after an ultrasonic bath. The femtosecond fabrication technique used has been introduced in [7,16]. The SEM micrographs on the region fabricated by femtosecond processing are shown in Fig. 1. The mesh spacing is 300 μm for the alignment of laser irradiation during LIDT. The pit spacing is 18 μm, with lateral size of ~7 μm and vertical size of 3 μm. Further observation with cross-sections of the pits by a focus ion beam showed no crack below the pits.
HR coatings with a multilayer structure Sub/4L(HL)\(^{11}\) H4L/air were deposited on the substrates with and without the femtosecond laser fabricated pits. HfO\(_2\) and SiO\(_2\) are chosen as high- (H) and low- (L) refractive index materials, and H and L have a quarter-wave optical thickness at the reference wavelength of 1064 nm.

LIDT testing was performed in the “1-on-1” regime according to the ISO standard 21254-1, using a pulsed Nd:YAG laser operating with a pulse duration of 12 ns at 1064 nm with normal incident angle. The experimental setup was detailed in Refs. [17, 18]. The laser radiation at the sample plane had a near-Gaussian spatial profile with an effective diameter of about 397 \(\mu\)m. The damage morphologies were characterized by a focused ion beam-scanning electron microscope (FIB-SEM, Carl Zeiss AURIGA Cross Beam).

The typical morphology of the coatings on the pits was observed by SEM and a cross-section of the pits by FIB shown in Fig. 2. For the 1064 nm HR coatings, structural defect (length: \(\sim 7\) \(\mu\)m; width: \(\sim 3\) \(\mu\)m; depth: 800 nm), cracks were observed in the relatively deeper layer of the film, which resulted in a discontinuous geometric structure. The LIDT testing of the two kinds of samples were evaluated and compared, as shown in Fig. 3.

The pits on the substrate significantly decreased the LIDT of the HR coatings. The damage in the HR coatings of the samples without pits was extremely rare. As shown in Fig. 4 a single shot of 1064-nm laser with high fluence of 151 J/cm\(^2\) caused a small nodule ejection morphology with a large area of plasma scald. However, damage of the HR coatings was observed after laser irradiation with fluence of 40 J/cm\(^2\), which also showed the morphology of plasma scald whose source is definitely located in the position of pit defects. As shown in Fig. 5, the groove bottom of the pit site on coating surface was seriously damaged with the irradiation of low laser fluence, and the meltdown mostly occurred possibly because of the rapid elevation of temperature during the irradiation induced by E-field intensification. After high fluence laser irradiation, the negative impact of cracks in deep coating layers are obvious, which is observed by FIB (Fig. 5).

To elucidate, if the substrate pits can lead to E-field intensification within the HR coatings, a cross-sectional image of HfO\(_2\)/SiO\(_2\) was used to estimate the E-field distribution by finite element method (FEM). The distribution images of E-field intensity \(|E|\)\(^2\) were plotted in

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**Fig. 1.** SEM micrographs of the rectangular mesh fabricated by 800-nm-femtosecond laser.

**Fig. 2.** Typical morphology of HR coatings with pits by SEM. (A) and (C) Cross-section of the pits section. The yellow dashed line indicates the interface of the film and the substrate. (B) Surface morphology of pits section after e-beam deposition.

**Fig. 3.** 1-on-1 LIDT testing result of HR coatings deposited on substrate with and without pits.

**Fig. 4.** (A) SEM microgram of the damage site of HR coatings deposited on the fused silica without pits at fluence of 151 J/cm\(^2\); (B) cross-section of the damage site.

**Fig. 5.** (A) SEM microgram of the damage site of HR coatings deposited on the fused silica with pits at low fluence of 40 J/cm\(^2\); (B) cross-section of the damage site (A). (C) SEM microgram of the damage site of HR coatings deposited on the fused silica with pits at high fluence of 120 J/cm\(^2\); (D) cross-section of the damage site (C).
The HR coatings changes its morphology accordingly while trying to recover its flatness. The profile of refractive index was got by image process with SEM-FIB figure. The refractive index values (1.45 for SiO$_2$ and 1.94 for HfO$_2$) are estimated by the commercial thin-film design software Essential Macleod. As shown in Figs. 6 and 8(D), the highest E-field intensifications are located at the groove bottom of the pit site in air/film interface. The pit defects resulted in an $|E|^2$ enhancement that was $\sim$17 times higher than the incident field strength near the interface of air and film. The distorted coatings caused by the existence of the pit in the substrate easily caused damage when irradiated by a laser. The temperature distribution in the whole laser irradiated region [19] shown in Fig. 7 can be described as (1).

$$C_n \left( \frac{\partial T(r, z, t)}{\partial t} \right) - K_n \nabla^2 T(r, z, t) = Q(r, z, t);$$

$$\frac{\partial T(r, z = 0, t)}{\partial t} = \gamma T(r, z = 0, t);$$

$$T(r, z = \infty, t) = T(r = \infty, z, t) = 0;$$

$$T(r, z, t = 0) = 0,$$

where $C_n$ is the specific heat, $K_n$ is the heat conductivity, $\gamma$ is heat exchange coefficient, and $Q(r, z, t)$ is the heat generated by absorption both from layers and interfaces. Without considering the absorptive defects in multilayer coatings, the intrinsic damage threshold is limited by the electric-field-induced thermal damage of the coating materials. The extinction coefficient of the adhesion layer is much higher than the intrinsic parameter [20–23]. The extinction coefficient used in the simulation were $7 \times 10^{-5}$ for HfO$_2$, $1 \times 10^{-5}$ for SiO$_2$, $5 \times 10^{-2}$ for the interface of layer/layer, and $8 \times 10^{-2}$ for the interface of air/layer. The structure with pits reached a much higher temperature gradient when irradiated by the same laser fluence. In addition, cracks were observed in the coatings, and stress damage occurred more easily when...
the temperature gradient was larger. This is the reason why the bottom region of the coatings is easily damaged with low fluence.

The damage caused by substrate pits on HR coatings upon laser exposure could be explained by different factors. According to the thermal transfer theory, a phenomenological model is proposed to describe the formation of the damage. As shown in Figs. 8 and 9, irradiation by low fluence laser pulse heated the air/SiO$_2$ interface of pit defect into a high temperature. As a result, an extremely unstable nanoabsorbing center is revealed by pit surface meltdown. When the irradiation fluence increase, the range of damage increases both laterally and vertically with expanding plasma scalld. When the damage penetrates into the cracked region, the damage extended into the substrate very quickly, which eventually lead to destruction of the multilayer structure.

In this experiment, pits on the substrate were fabricated using a femtosecond laser, which dictated the modulation of a high-reflector multilayer geometry, and can lead to electrical-field amplification and reduced laser damage resistance. The cause of damage on the HR coatings with pits is the combination of electric field intensification, temperature rising, and stress release of crack in the thin film. Moreover, pits defects of $\sim$3 $\mu$m in width and $\sim$800 nm in depth were fabricated and tested, which was particularly easy to generate damage on HR coatings over the range of fluence tested in this study. The combination of E-field and intensification and poor mechanic structure (internal cracks in HR coatings) eventually induced the catastrophic damage. Through this work, we have ascertained that the micro-scale pits on the substrate are one of the sources of damage on thin film. It could not be ignored, and much more attention should be deserved, which can help researchers improve the LIDT of optical film coatings.

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